

Seat No: AF12696

PARUL UNIVERSITY
FACULTY OF ENGINEERING & TECHNOLOGY
B.Tech. Winter 2023-24 Examination

Enrollment No: 2303031050270

Semester: 1/2

Subject Code: 303192102

Subject Name: Engineering Physics-II

Date: 23-01-2024

Time: 02:00 pm to 04:30 pm

Total Marks: 60

Instructions:

1. All questions are compulsory.
2. Figures to the right indicate full marks.
3. Make suitable assumptions wherever necessary.
4. Start new question on new page.

Q.1 Objective Type Questions -

(Each of one mark)

(15)

1. Nano tube is _____ material.
(a) one dimensional (b) two dimensional
(c) three dimensional (d) none of the above.
2. Fermi energy level for P type semiconductors lies _____
(a) At middle of the band gap (b) Close to conduction band
(c) Close to valence band (d) Can not predict
3. _____ means a minute piece of matter with defined physical boundaries.
(a) Particle (b) Aggregate (c) Agglomerate (d) None
4. Which of the following is not a pumping process?
(a) Optical pumping (b) Electrical pumping
(c) Chemical pumping (d) Thermal pumping
5. _____ are commonly defined as materials with an average grain size less than 100nm.
(a) semiconductors (b) nano materials (c) Quantum materials (d) None of the above
6. If Ψ is the wave function, the probability density function is given by _____
($|\Psi|^2 / |\Psi|^3$)
7. In _____ (direct/indirect) band gap materials, momentum is conserved when electron makes transition from conduction band to valence band.
8. Write full form of LASER.
9. The _____ (Critical angle / Numerical Aperture) is a measure of the light-collecting ability of the fiber.
10. The optoelectronic device whose resistivity is the function of input intensity is _____ (Photo conductive cell/ LED)
11. $Q_{op}\psi_i = q_i\psi_i$ represents eigen value equation. (where Q is operator, ψ_i is the wave function)
a) True b) False
12. One-dimensional material has confinement in _____ dimensions and mobility in _____ dimensions.
13. AlGaInP is _____ form of compound materials. (Ternary/Quaternary)
14. Define Aggregate and Agglomerate.
15. Define Bandgap.

Q.2 Answer the following questions. (Attempt any three)

(15)

- A) Explain the Physical significance of a Wave Function.
- B) Explain E-K diagram with Direct and Indirect Bandgap.
- C) Discuss the properties of LASER.
- D) Write about photo Voltaic cell.

Q.3 A) Derive an expression for Schrodinger time independent wave equation.

(07)

B) Explain the construction, working, energy band diagram, and application of Ruby laser. (08)

OR

B) (i) Write a note on Light Emitting Diodes. (08)

(ii) Calculate the energy of ejected photoelectron for the incident photon energy of 5 eV. The threshold energy of the photosensitive metal is 3.2 eV.

Q.4 A) Explain the concept of effective mass and derive the equation of effective mass of electron in valance band and conduction band. (07)

OR

A) Discuss all 3 types of photo detectors. (07)

B). Discuss stimulated absorption, spontaneous emission and stimulated emission. (08)